

# BGX7221

## Dual receiver down mixer

Rev. 3 — 8 August 2012

Product data sheet

## 1. General description

The BGX7221 device combines a pair of high performance, high linearity down-mixers for use in receivers having a common local oscillator, for instance having main and diversity paths. The device covers the frequency range from 1400 MHz to 2700 MHz. Each mixer provides an input 1 dB compression point ( $ICP_{1dB}$ ) above 13 dBm, with an input third-order intercept point ( $IP3_i$ ) of 26 dBm. The small-signal Noise Figure (NF) is at 10 dB whereas under large signal blocking conditions the Noise Figure is typically 20 dB. Isolation between mixers is typically 55 dB.

## 2. Features and benefits

- 1400 MHz to 2700 MHz frequency operating range
- Conversion gain 8 dB in the 2 GHz band
- 13 dBm input power at 1 dB gain compression point
- 26 dBm input third-order intercept point
- 10 dB typical small signal noise figure
- Integrated active biasing
- 5 V single supply operation
- Independent power-down hardware control pins per mixer
- Low bias current in Power-down mode
- Matched 50 Ω single-ended RF and LO input impedance
- ESD protection at all pins

## 3. Applications

- Mobile network infrastructure
- RF and IF applications
- Communication systems and radars
- Microwave and broadband
- Industrial applications

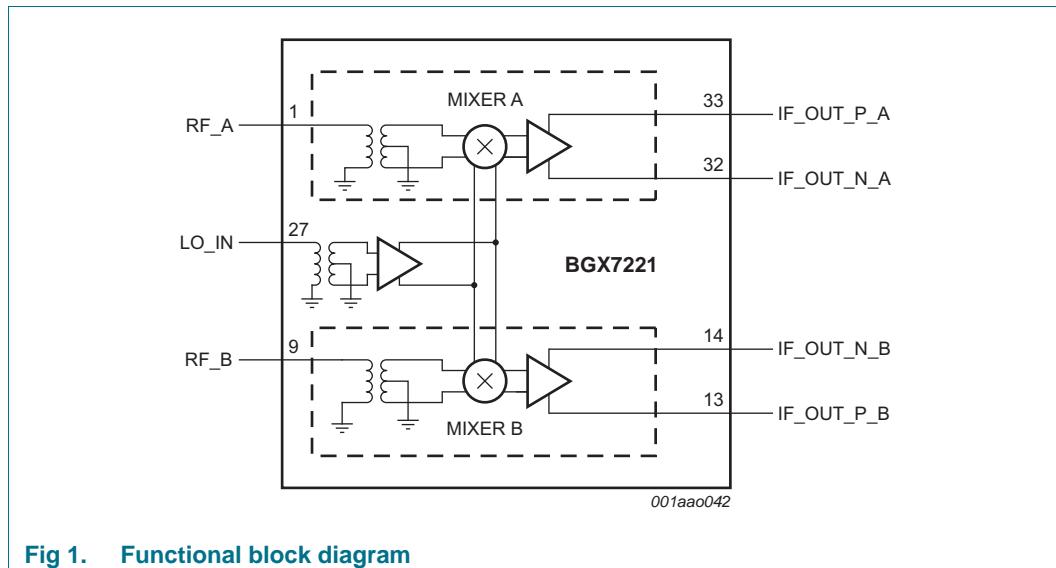
## 4. Ordering information

Table 1. Ordering information

Type number	Package			Version
	Name	Description		
BGX7221HN	HVQFN36	plastic thermal enhanced very thin quad flat package; no leads; 36 terminals; body 6 × 6 × 0.85 mm		SOT1092-2



## 5. Functional diagram



**Fig 1. Functional block diagram**

Each mixer, A and B employs a transformer to convert the single-ended RF input into a differential signal to drive the passive MOS mixer. The MOS mixer directly drives the IF amplifier. Its open-collector outputs deliver the differential signal into an external transformer load, referenced to the 5 V supply for maximum signal swing. Each mixer can be independently powered-off by a combination of POFF\_1 and POFF\_2 (see [Table 3.](#)) The dual paths allow diversity operation with a common LO path. A transformer at the LO input converts the single-ended RF into a differential signal to drive the LO buffer chain.

The plastic package has an under-side heat-sink paddle which serves as a good RF ground.

## 6. Pinning information

### 6.1 Pinning

Viewing the device from the top (see [Figure 2](#)), the 2 RF input ports are at the left, the common LO input at the right, with IF outputs at the top and bottom. Multiple power and ground pins allow for independent supply domains to improve isolation between blocks.

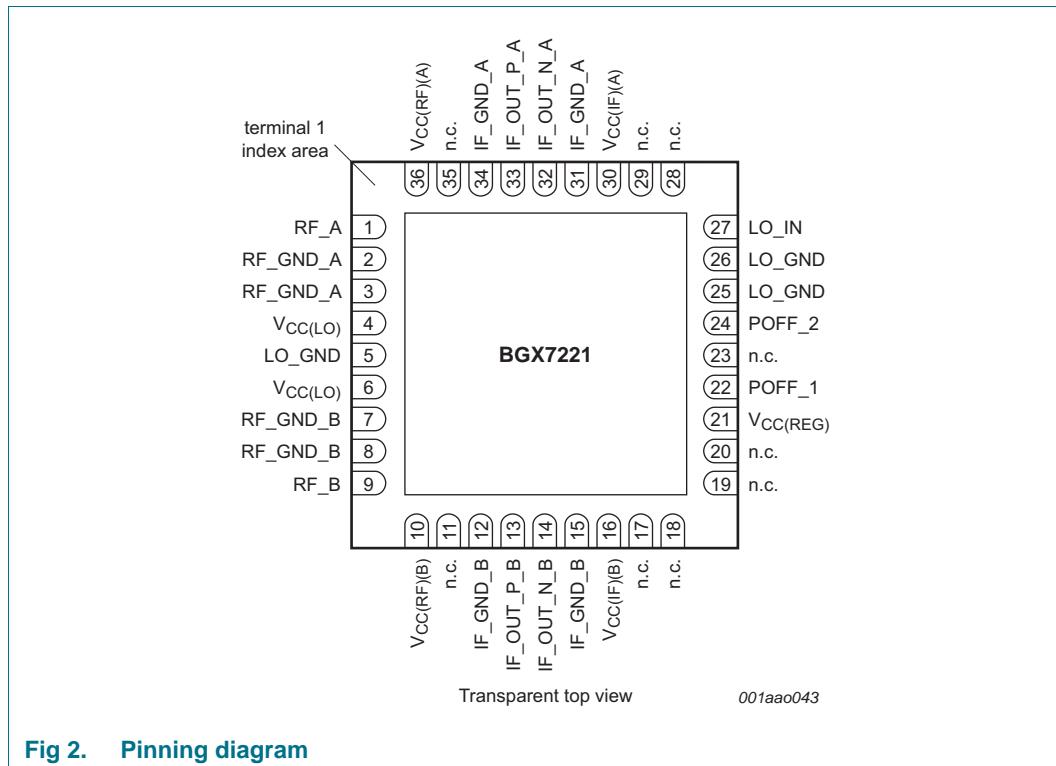


Fig 2. Pinning diagram

## 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Type <sup>[1]</sup>	Description
RF_A	1	I	receiver mixer single-ended RF input; mixer A
RF_GND_A	2	G	RF ground; mixer A
RF_GND_A	3	G	RF ground; mixer A
V <sub>CC</sub> (LO)	4	P	LO power supply
LO_GND	5	G	LO ground
V <sub>CC</sub> (LO)	6	P	LO power supply
RF_GND_B	7	G	RF ground; mixer B
RF_GND_B	8	G	RF ground; mixer B
RF_B	9	I	receiver mixer single-ended RF input; mixer B
V <sub>CC</sub> (RF)(B)	10	P	RF mixer power supply; mixer B
n.c.	11	-	not connected; to be tied to ground
IF_GND_B	12	G	IF ground; mixer B
IF_OUT_P_B	13	O	symmetrical IF positive output signal; mixer B
IF_OUT_N_B	14	O	symmetrical IF negative output signal; mixer B
IF_GND_B	15	G	IF amplifier ground; mixer B
V <sub>CC</sub> (IF)(B)	16	P	IF amplifier power supply; mixer B
n.c.	17	-	not connected; to be tied to ground
n.c.	18	-	not connected; to be tied to ground
n.c.	19	-	not connected; to be tied to ground
n.c.	20	-	not connected; to be tied to ground

**Table 2.** Pin description ...*continued*

Symbol	Pin	Type <sup>[1]</sup>	Description
V <sub>CC(REG)</sub>	21	P	internal regulator power supply
POFF_1	22	I	logic input to power-off mixer
n.c.	23	-	not connected; to be tied to ground
POFF_2	24	I	logic input to power-off mixer
LO_GND	25	G	LO ground
LO_GND	26	G	LO ground
LO_IN	27	I	single-ended local oscillator positive input
n.c.	28	-	not connected; to be tied to ground
n.c.	29	-	not connected; to be tied to ground
V <sub>CC(IF)(A)</sub>	30	P	IF amplifier power supply; mixer A
IF_GND_A	31	G	IF amplifier mixer; mixer A
IF_OUT_N_A	32	O	symmetrical IF negative output; mixer A
IF_OUT_P_A	33	O	symmetrical IF positive output; mixer A
IF_GND_A	34	G	IF ground; mixer A
n.c.	35	-	not connected; to be tied to ground
V <sub>CC(RF)(A)</sub>	36	P	RF power supply; mixer A
Exposed paddle	-	G	exposed paddle; must be connected to RF and DC ground

[1] G: ground; I: input; O: output; P: power.

## 7. Functional description

### 7.1 Power-up control

**Table 3.** Shutdown control

Mode	Description	Function	POFF_1	POFF_2
Active	mixers A and B active	shutdown disabled	0	0
Idle	mixers A and B OFF; current supplied to LO buffer	shutdown enabled	1	0
Main	mixer A active; mixer B OFF	partial shutdown	0	1
Diversity	mixer B active; mixer A OFF	partial shutdown	1	1

Power-up enable pins to allow each mixer to be placed in Power-down mode. These pins also enable the dedicated LO buffers for individual signal paths. A common LO input stage remains active whatever the state of the power off control inputs, in order to maintain good LO port matching. The time required to pass between active and inactive states is less than 10 µs. If the pins are left open or tied to ground, both mixers will be in active state.

## 8. Limiting values

**Table 4. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	supply voltage		-0.3	+5.5	V
P <sub>i(RF)</sub>	RF input power	continuous	-	20	dBm
P <sub>tot</sub>	total power dissipation		-	2.5	W
T <sub>mb</sub>	mounting base temperature		-40	+85	°C
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C
V <sub>ESD</sub>	electrostatic discharge voltage	EIA/JESD22-A114 (HBM) EIA/JESD22-C101 (FCDM)	-2500 -650	+2500 +650	V

## 9. Thermal characteristics

**Table 5. Thermal characteristics**

Symbol	Parameter	Conditions	Typ	Unit
R <sub>th(j-mb)</sub>	thermal resistance from junction to mounting base	[1]	8	°C/W

[1] Defined according to the conditions described in the Application Note AN10998.

## 10. Static characteristics

**Table 6. Static characteristics**Z<sub>s</sub> = Z<sub>L</sub> = 50 Ω; POFF\_1 = V<sub>IL</sub> and POFF\_2 = V<sub>IH</sub> (shutdown disabled). Typical values at V<sub>CC</sub> = 5 V, T<sub>mb</sub> = 25 °C, unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
V <sub>CC</sub>	supply voltage		4.75	5.0	5.25	V	
I <sub>Cq</sub>	quiescent collector current	IF output; per package pin	[1]	-	60	-	mA
<b>Shutdown digital input voltage</b>							
V <sub>IL</sub>	LOW-level input voltage		[1]	0	-	0.5	V
V <sub>IH</sub>	HIGH-level input voltage		[1]	2	-	5	V
<b>All digital inputs current</b>							
I <sub>IL</sub>	LOW-level input current		[1]	-	1	-	μA
I <sub>IH</sub>	HIGH-level input current		[1]	-	50	-	μA

[1] V<sub>CC</sub> = 4.75 V to 5.25 V, T<sub>mb</sub> = -40 °C to +85 °C.

## 11. Dynamic characteristics

**Table 7. Dynamic characteristics**

Typical application values:  $P_{OFF\_1} = V_{IL}$  and  $P_{OFF\_2} = V_{IL}$  (shutdown disabled); RF and LO ports driven by  $50 \Omega$  sources; unless otherwise specified.

Symbol	Parameter	Conditions	Min <sup>[1]</sup>	Typ <sup>[2]</sup>	Max <sup>[1]</sup>	Unit
$I_{CC}$	supply current	both mixers in active mode				
		$f_{RF} = 1400$ MHz	-	320	370	mA
		$f_{RF} = 1700$ MHz	-	330	380	mA
		$f_{RF} = 1900$ MHz	-	340	390	mA
		$f_{RF} = 2700$ MHz	-	365	420	mA
$f_{i(RF)}$	RF input frequency		[3]	1400	-	2700 MHz
$f_{lo}$	local oscillator frequency	signal from frequency generator; $f_{IF} = 100$ MHz to 300 MHz	[3]	1500	-	2500 MHz
$P_{i(lo)}$	local oscillator input power	signal from frequency generator	[3]	-3	-	+3 dBm
$G_{conv}$	conversion gain	at $T_{mb} = 25$ °C; $f_{i(RF)} = 1400$ MHz to 2700 MHz	[4]	6.8	8	9.5 dB
$\Delta G/\Delta T$	gain variation with temperature	$T_{mb} = -40$ °C to +85 °C	-	0.011	-	dB/°C
$\Delta G$	gain deviation	$f_{i(RF)} = 1400$ MHz to 1465 MHz; $f_{lo} = 1245$ MHz	[4][5]	-	0.2	- dB
		$f_{i(RF)} = 1710$ MHz to 1785 MHz; $f_{lo} = 1550$ MHz	[4][5]	-	0.3	- dB
		$f_{i(RF)} = 1850$ MHz to 1910 MHz; $f_{lo} = 1680$ MHz	[4][5]	-	0.25	- dB
		$f_{i(RF)} = 1920$ MHz to 1980 MHz; $f_{lo} = 1750$ MHz	[4][5]	-	0.25	- dB
		$f_{i(RF)} = 2300$ MHz to 2400 MHz; $f_{lo} = 2150$ MHz	[4][5]	-	0.4	- dB
		$f_{i(RF)} = 2500$ MHz to 2570 MHz; $f_{lo} = 2335$ MHz	[4][5]	-	0.25	- dB
		$f_{i(RF)} = 2570$ MHz to 2620 MHz; $f_{lo} = 2395$ MHz	[4][5]	-	0.2	- dB
$ICP_{1dB}$	1 dB input compression point		[6]	12.5	14	- dBm
$IP3_i$	input third-order intercept point	$f_{i(RF)1}$ to $f_{i(RF)2} = 1$ MHz; $P_{i(RF)} = -5$ dBm per tone	[4]	24	25.5	- dBm
2RF-2LO	second-order spurious rejection	2 tone inputs at $P_{LO} = 0$ dBm; $f_{i(RF)} = 2100$ MHz; $f_{i(LO)} = 1900$ MHz; $f_{i(SPUR)} = 2000$ MHz	-54	-60	-	dBc
$NF_{SSB}$	single sideband noise figure	$f_{i(RF)} = 1400$ MHz to 2200 MHz	-	10	12	dB
		$f_{i(RF)} = 2200$ MHz to 2700 MHz	-	10.5	12.5	dB
$NF_B$	noise figure under blocking conditions	input in-band blocker +8 dBm; $\Delta f_o = 100$ MHz	[7]	-	20	- dB
$\alpha_{L(RF)lo}$	local oscillator RF leakage	at RF input port	-	-	-30	dBm
$\alpha_{L(IF)lo}$	local oscillator IF leakage	at IF output port	-	-	-30	dBm

**Table 7. Dynamic characteristics ...continued**

Typical application values:  $P_{OFF\_1} = V_{IL}$  and  $P_{OFF\_2} = V_{IL}$  (shutdown disabled); RF and LO ports driven by  $50 \Omega$  sources; unless otherwise specified.

Symbol	Parameter	Conditions	Min <sup>[1]</sup>	Typ <sup>[2]</sup>	Max <sup>[1]</sup>	Unit
$\alpha_{isol}$	isolation	between mixer A and B; $P_{i(RF)} = -10 \text{ dBm}$ ; measured at unwanted IF port	45	55	-	dB
S11_RF	RF input return loss	$f_{i(RF)} = 1400 \text{ MHz}$ to $2700 \text{ MHz}$	-	12	-	dB
S11_LO	LO input return loss	$f_{lo} = 1200 \text{ MHz}$ to $2500 \text{ MHz}$	-	12	-	dB
S22_IF	IF output return loss	$f_{IF} = 100 \text{ MHz}$ to $300 \text{ MHz}$	-	14	-	dB

[1] For all minimum and maximum values the conditions are:  $P_{i(RF)} = -5 \text{ dBm}$ ;  $P_{i(lo)} = 0 \text{ dBm}$ ;  $f_{i(RF)} = 1900 \text{ MHz}$ ;  $f_{lo} = 1700 \text{ MHz}$ ;  $f_{IF} = 200 \text{ MHz}$ ;  $T_{mb} = -40^\circ\text{C}$  to  $+85^\circ\text{C}$ ;  $V_{CC} = 4.75 \text{ V}$  to  $5.25 \text{ V}$ . Unless otherwise specified in the conditions.

[2] For all typical values, the conditions are:  $P_{i(RF)} = -5 \text{ dBm}$ ;  $P_{lo} = 0 \text{ dBm}$ ;  $f_{i(RF)} = 1900 \text{ MHz}$ ;  $f_{lo} = 1700 \text{ MHz}$ ;  $f_{IF} = 200 \text{ MHz}$ ;  $T_{mb} = 25^\circ\text{C}$ ;  $V_{CC} = 5 \text{ V}$ . Unless otherwise specified in the conditions.

[3] Operation outside this range is possible but parameters are not guaranteed.

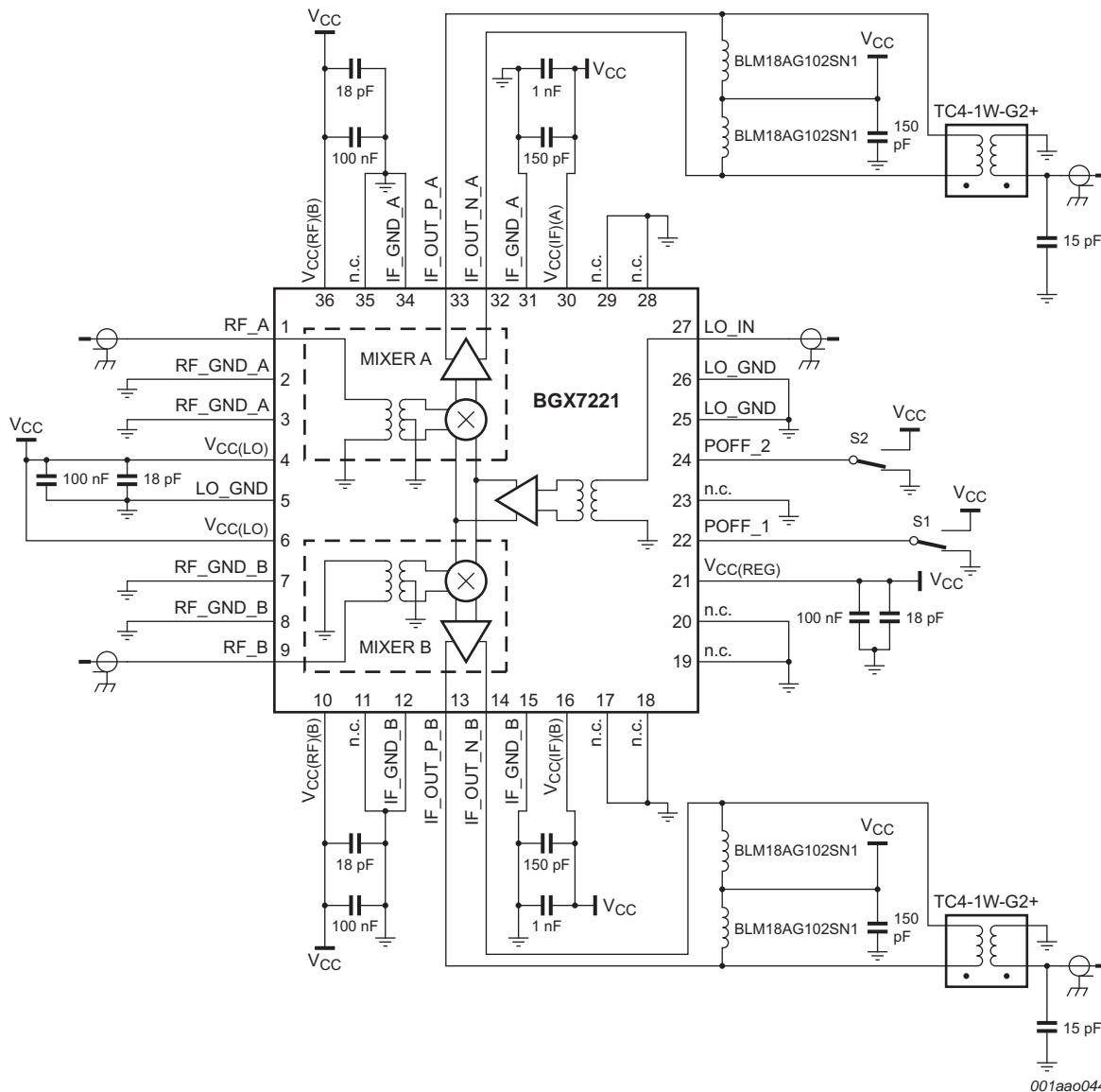
[4] Class A operation.

[5]  $f_{IF}$  is variable.

[6] Maximum reliable continuous input power applied to the RF or IF port of this device is 12 dBm from a  $50 \Omega$  source.

[7]  $NF_B$  can be improved by 1 dB per dB as a function of the  $P_{i(lo)}$ .

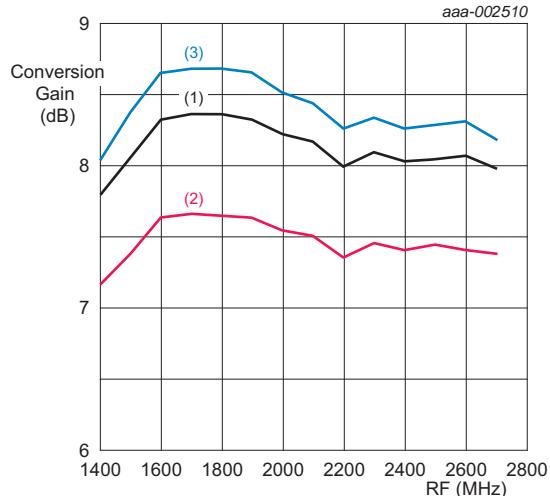
## 12. Application information



**Fig 3. Application diagram**

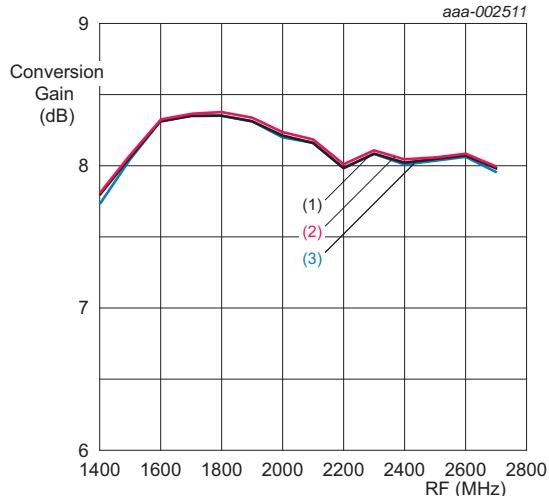
Figure 3 shows a typical application circuit. Both RF and RF reference pins need to be AC coupled. The inputs are internally DC biased in order to provide good ESD protection, and to support large input signals without clamping. The output matching requires a transformer to cope with the DC at the output.

## 13. Test information



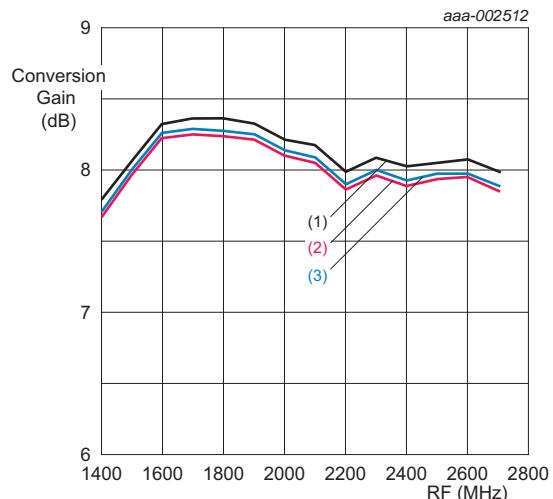
- (1)  $T_{mb} = +25\text{ }^{\circ}\text{C}$ .
- (2)  $T_{mb} = +85\text{ }^{\circ}\text{C}$ .
- (3)  $T_{mb} = -40\text{ }^{\circ}\text{C}$ .

**Fig 4.**  $G_{conv}$  versus  $f_{RF}$  and  $T_{mb}$



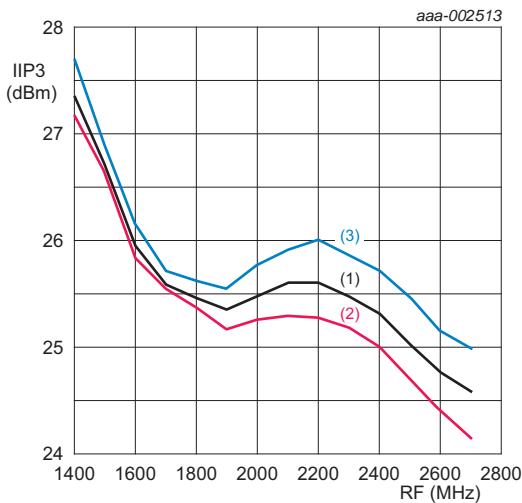
- (1)  $P_{i(lo)} = 0\text{ dBm}$ .
- (2)  $P_{i(lo)} = +3\text{ dBm}$ .
- (3)  $P_{i(lo)} = -3\text{ dBm}$ .

**Fig 5.**  $G_{conv}$  versus  $f_{RF}$  and  $P_{i(lo)}$

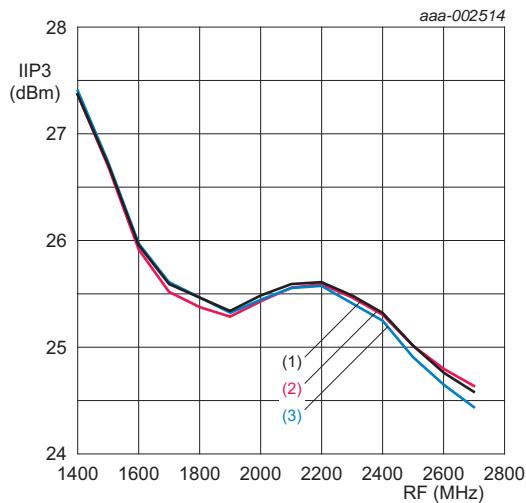


- (1)  $V_{CC} = 5\text{ V}$ .
- (2)  $V_{CC} = 5.25\text{ V}$ .
- (3)  $V_{CC} = 4.75\text{ V}$ .

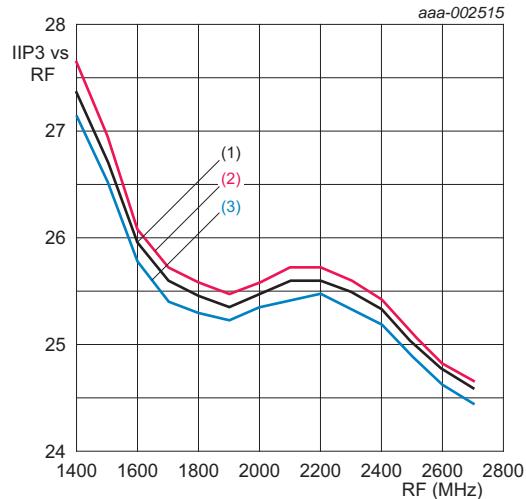
**Fig 6.**  $G_{conv}$  versus  $f_{RF}$  and  $V_{CC}$



- (1)  $T_{mb} = +25 \text{ }^{\circ}\text{C}$ .
- (2)  $T_{mb} = +85 \text{ }^{\circ}\text{C}$ .
- (3)  $T_{mb} = -40 \text{ }^{\circ}\text{C}$ .

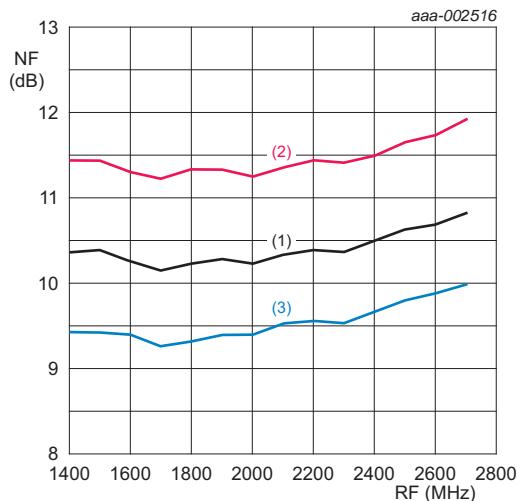
Fig 7. IP3<sub>i</sub> versus f<sub>RF</sub> and T<sub>mb</sub>

- (1)  $P_{i(l)} = 0 \text{ dBm}$ .
- (2)  $P_{i(l)} = +3 \text{ dBm}$ .
- (3)  $P_{i(l)} = -3 \text{ dBm}$ .

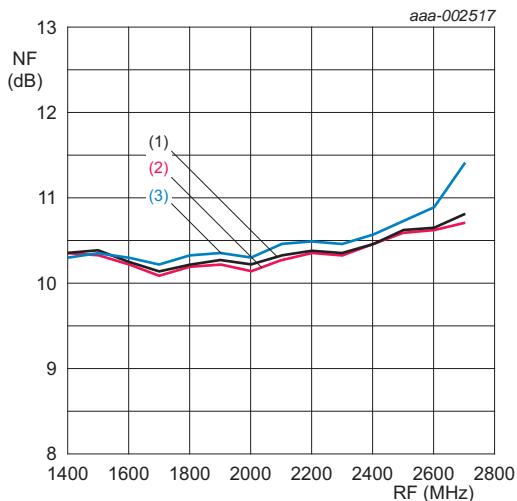
Fig 8. IP3<sub>i</sub> versus f<sub>RF</sub> and P<sub>i(l)</sub>

- (1)  $V_{CC} = 5 \text{ V}$ .
- (2)  $V_{CC} = 5.25 \text{ V}$ .
- (3)  $V_{CC} = 4.75 \text{ V}$ .

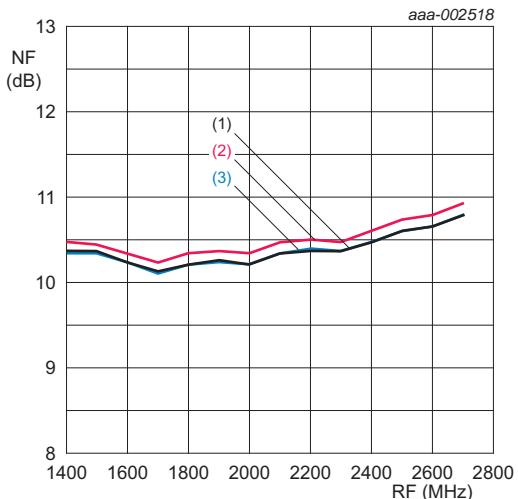
Fig 9. IP3<sub>i</sub> versus f<sub>RF</sub> and V<sub>CC</sub>



- (1)  $T_{mb} = +25 \text{ }^{\circ}\text{C}$ .
- (2)  $T_{mb} = +85 \text{ }^{\circ}\text{C}$ .
- (3)  $T_{mb} = -40 \text{ }^{\circ}\text{C}$ .

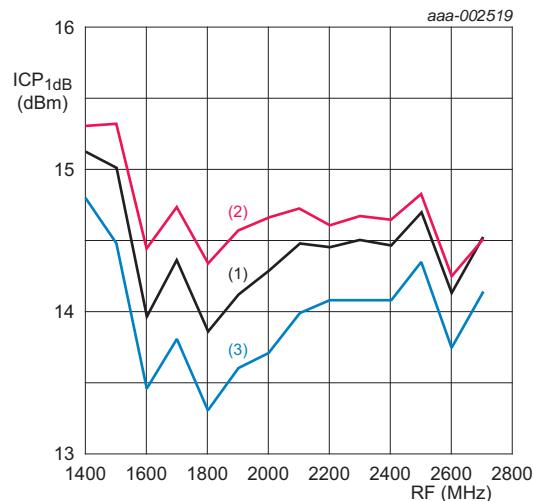
Fig 10. NF versus f<sub>RF</sub> and T<sub>mb</sub>

- (1)  $P_{i(\text{Lo})} = 0 \text{ dBm}$ .
- (2)  $P_{i(\text{Lo})} = +3 \text{ dBm}$ .
- (3)  $P_{i(\text{Lo})} = -3 \text{ dBm}$ .

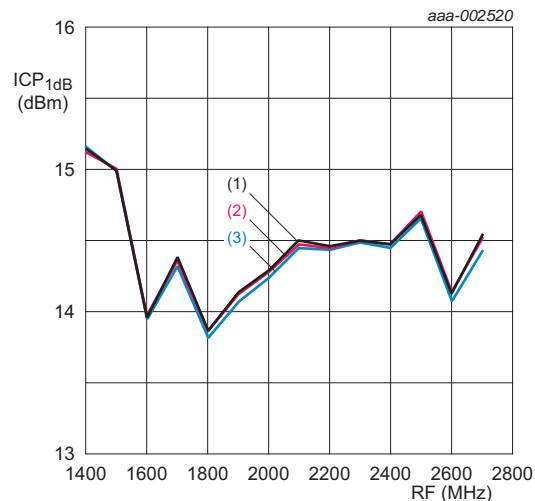
Fig 11. NF versus f<sub>RF</sub> and P<sub>i(Lo)</sub>

- (1)  $V_{CC} = 5 \text{ V}$ .
- (2)  $V_{CC} = 5.25 \text{ V}$ .
- (3)  $V_{CC} = 4.75 \text{ V}$ .

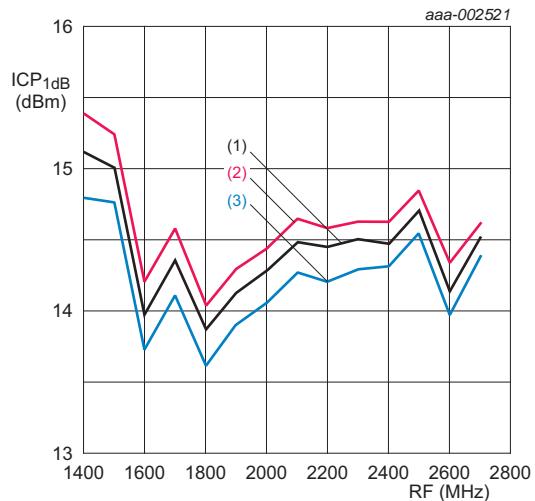
Fig 12. NF versus f<sub>RF</sub> and V<sub>CC</sub>



- (1) T<sub>mb</sub> = +25 °C.
- (2) T<sub>mb</sub> = +85 °C.
- (3) T<sub>mb</sub> = -40 °C.

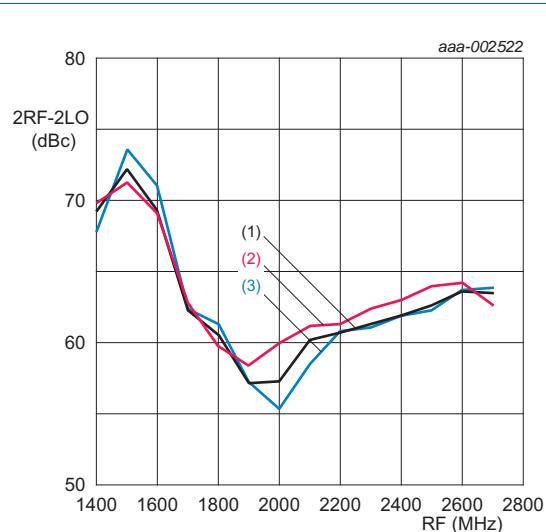
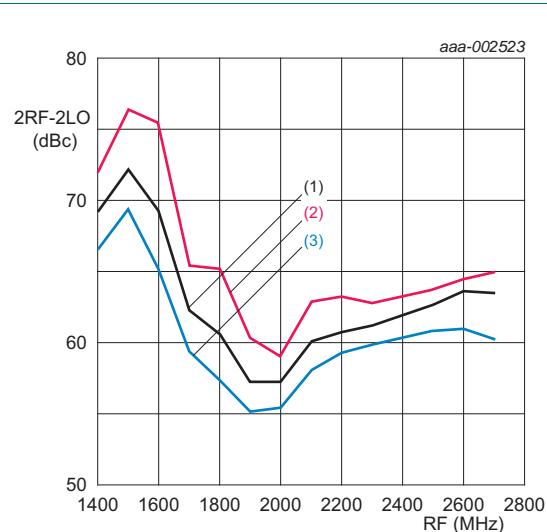
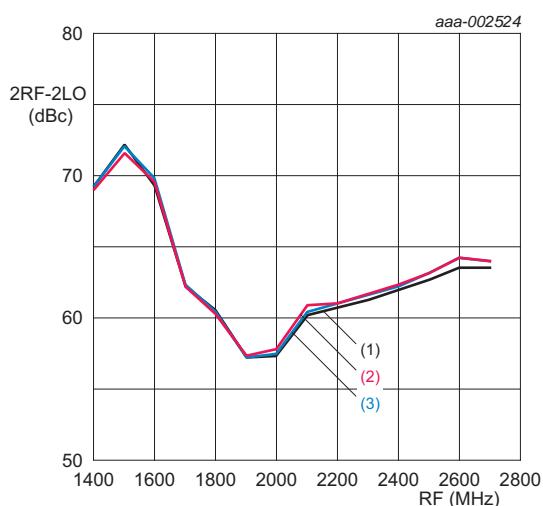
**Fig 13. ICP<sub>1dB</sub> versus f<sub>RF</sub> and T<sub>mb</sub>**

- (1) P<sub>i(Lo)</sub> = 0 dBm.
- (2) P<sub>i(Lo)</sub> = +3 dBm.
- (3) P<sub>i(Lo)</sub> = -3 dBm.

**Fig 14. ICP<sub>1dB</sub> versus f<sub>RF</sub> and P<sub>i(Lo)</sub>**

- (1) V<sub>CC</sub> = 5 V.
- (2) V<sub>CC</sub> = 5.25 V.
- (3) V<sub>CC</sub> = 4.75 V.

**Fig 15. ICP<sub>1dB</sub> versus f<sub>RF</sub> and V<sub>CC</sub>**

Fig 16. 2RF-2LO response versus  $f_{RF}$  and  $T_{mb}$ Fig 17. 2RF-2LO response versus  $f_{RF}$  and  $P_{i(Io)}$ Fig 18. 2RF-2LO response versus  $f_{RF}$  and  $V_{CC}$

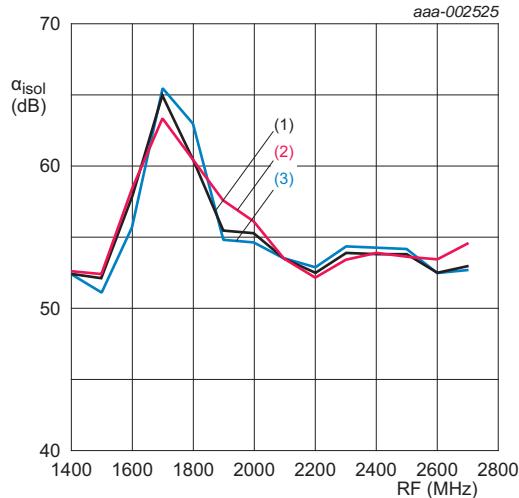


Fig 19.  $\alpha_{\text{isol}}$  versus  $f_{\text{RF}}$  and  $T_{\text{mb}}$

(1)  $T_{\text{mb}} = +25^{\circ}\text{C}$ .  
(2)  $T_{\text{mb}} = +85^{\circ}\text{C}$ .  
(3)  $T_{\text{mb}} = -40^{\circ}\text{C}$ .

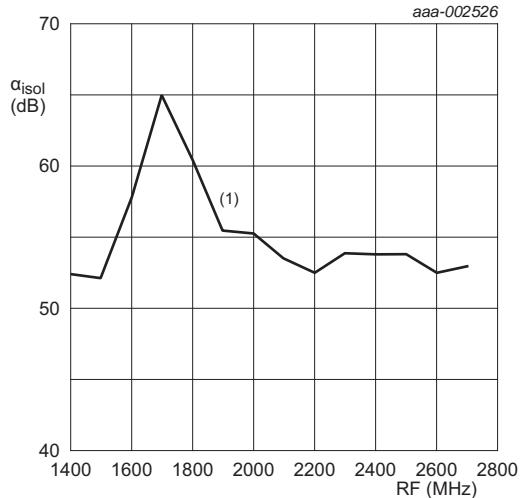


Fig 20.  $\alpha_{\text{isol}}$  versus  $f_{\text{RF}}$  and  $P_{\text{i}(lo)}$

(1)  $P_{\text{i}(lo)} = 0 \text{ dBm}$ .

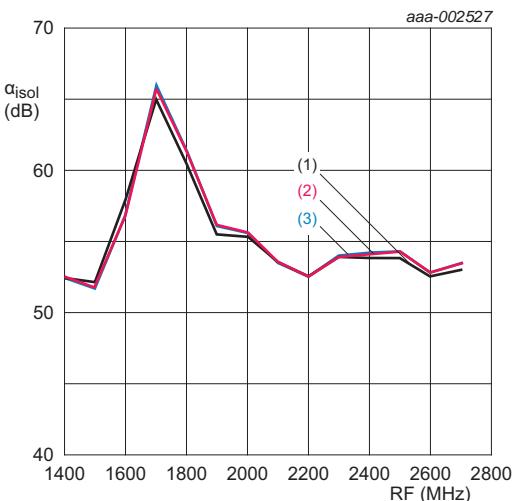


Fig 21.  $\alpha_{\text{isol}}$  versus  $f_{\text{RF}}$  and  $V_{\text{CC}}$

(1)  $V_{\text{CC}} = 5 \text{ V}$ .  
(2)  $V_{\text{CC}} = 5.25 \text{ V}$ .  
(3)  $V_{\text{CC}} = 4.75 \text{ V}$ .

## 14. Package outline

HVQFN36: plastic thermal enhanced very thin quad flat package; no leads;  
36 terminals; body 6 x 6 x 0.85 mm

SOT1092-2

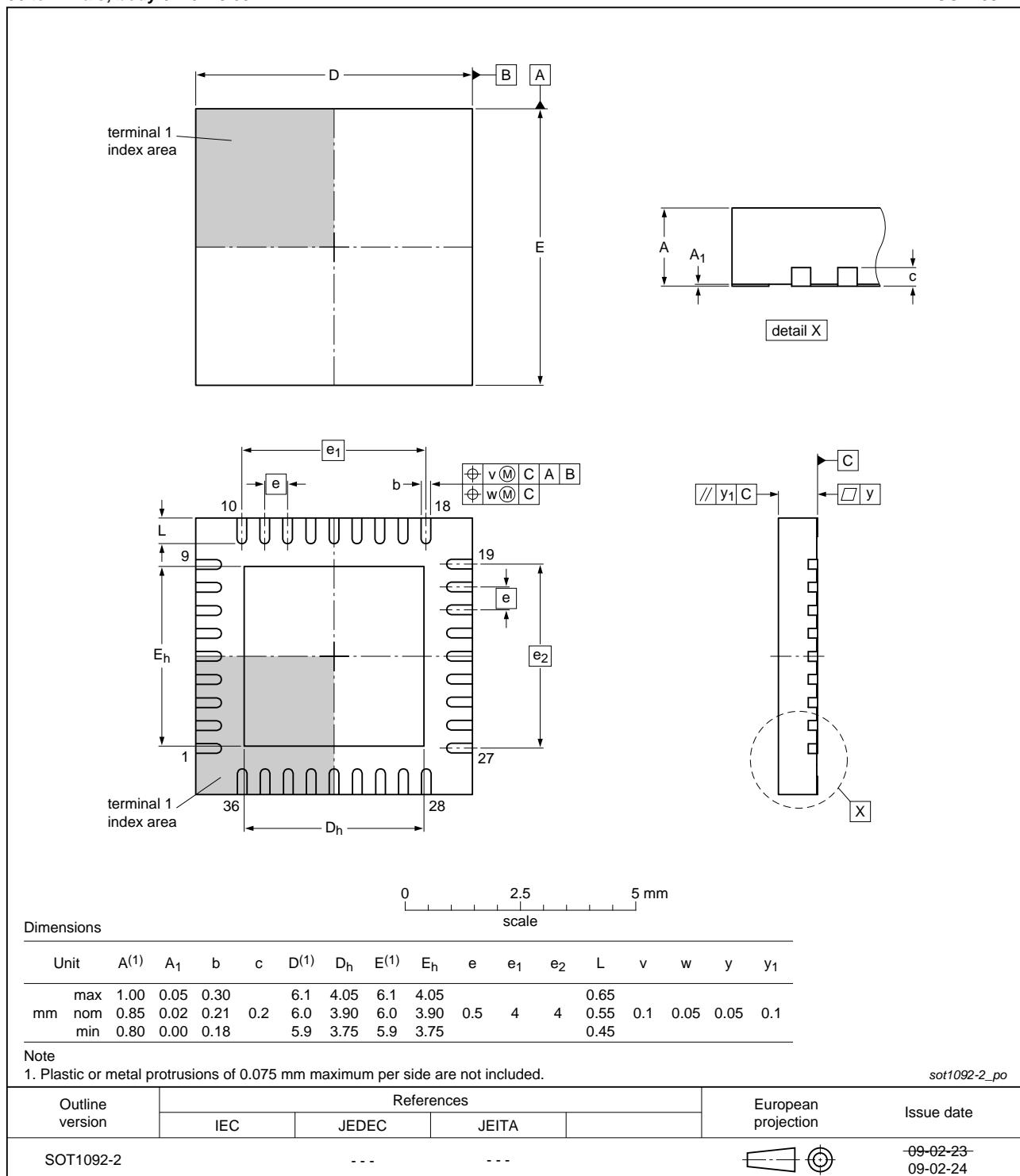


Fig 22. Package outline SOT1092-2 (HVQFN36)

## 15. Abbreviations

**Table 8. Abbreviations**

Acronym	Description
AC	Alternating Current
DC	Direct Current
ESD	ElectroStatic Discharge
FCDM	Field-induced Charged-Device Model
HBM	Human Body Model
IF	Intermediate Frequency
LO	Local Oscillator
MOS	Metal-Oxide Semiconductor
PCB	Printed-Circuit Board
RF	Radio Frequency

## 16. Revision history

**Table 9. Revision history**

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGX7221 v.3	20120808	Product data sheet	-	BGX7221 v.2
Modifications:		• <a href="#">Section 13</a> : added • <a href="#">Table 4</a> : updated • <a href="#">Table 7</a> : updated		
BGX7221 v.2	20120208	Preliminary data sheet	-	BGX7221 v.1
BGX7221 v.1	20110907	Objective data sheet	-	-

## 17. Legal information

### 17.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

### 17.2 Definitions

**Draft** — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

**Short data sheet** — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

**Product specification** — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

### 17.3 Disclaimers

**Limited warranty and liability** — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information. NXP Semiconductors takes no responsibility for the content in this document if provided by an information source outside of NXP Semiconductors.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

**Right to make changes** — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

**Suitability for use** — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in life support, life-critical or safety-critical systems or equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors and its suppliers accept no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

**Applications** — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Customers are responsible for the design and operation of their applications and products using NXP Semiconductors products, and NXP Semiconductors accepts no liability for any assistance with applications or customer product design. It is customer's sole responsibility to determine whether the NXP Semiconductors product is suitable and fit for the customer's applications and products planned, as well as for the planned application and use of customer's third party customer(s). Customers should provide appropriate design and operating safeguards to minimize the risks associated with their applications and products.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on any weakness or default in the customer's applications or products, or the application or use by customer's third party customer(s). Customer is responsible for doing all necessary testing for the customer's applications and products using NXP Semiconductors products in order to avoid a default of the applications and the products or of the application or use by customer's third party customer(s). NXP does not accept any liability in this respect.

**Limiting values** — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

**Terms and conditions of commercial sale** — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at <http://www.nxp.com/profile/terms>, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

**No offer to sell or license** — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

**Export control** — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from competent authorities.

**Non-automotive qualified products** — Unless this data sheet expressly states that this specific NXP Semiconductors product is automotive qualified, the product is not suitable for automotive use. It is neither qualified nor tested in accordance with automotive testing or application requirements. NXP Semiconductors accepts no liability for inclusion and/or use of non-automotive qualified products in automotive equipment or applications.

In the event that customer uses the product for design-in and use in automotive applications to automotive specifications and standards, customer (a) shall use the product without NXP Semiconductors' warranty of the product for such automotive applications, use and specifications, and (b) whenever customer uses the product for automotive applications beyond

NXP Semiconductors' specifications such use shall be solely at customer's own risk, and (c) customer fully indemnifies NXP Semiconductors for any liability, damages or failed product claims resulting from customer design and use of the product for automotive applications beyond NXP Semiconductors' standard warranty and NXP Semiconductors' product specifications.

**Translations** — A non-English (translated) version of a document is for reference only. The English version shall prevail in case of any discrepancy between the translated and English versions.

## 17.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

## 18. Contact information

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

## 19. Tables

Table 1.	Ordering information	1
Table 2.	Pin description	3
Table 3.	Shutdown control	4
Table 4.	Limiting values	5
Table 5.	Thermal characteristics	5
Table 6.	Static characteristics	5
Table 7.	Dynamic characteristics	6
Table 8.	Abbreviations	16
Table 9.	Revision history	16

## 20. Figures

Fig 1.	Functional block diagram	2
Fig 2.	Pinning diagram	3
Fig 3.	Application diagram	8
Fig 4.	$G_{\text{conv}}$ versus $f_{\text{RF}}$ and $T_{\text{mb}}$	9
Fig 5.	$G_{\text{conv}}$ versus $f_{\text{RF}}$ and $P_{i(\text{lo})}$	9
Fig 6.	$G_{\text{conv}}$ versus $f_{\text{RF}}$ and $V_{\text{CC}}$	9
Fig 7.	$\text{IP3}_i$ versus $f_{\text{RF}}$ and $T_{\text{mb}}$	10
Fig 8.	$\text{IP3}_i$ versus $f_{\text{RF}}$ and $P_{i(\text{lo})}$	10
Fig 9.	$\text{IP3}_i$ versus $f_{\text{RF}}$ and $V_{\text{CC}}$	10
Fig 10.	NF versus $f_{\text{RF}}$ and $T_{\text{mb}}$	11
Fig 11.	NF versus $f_{\text{RF}}$ and $P_{i(\text{lo})}$	11
Fig 12.	NF versus $f_{\text{RF}}$ and $V_{\text{CC}}$	11
Fig 13.	$\text{ICP}_{1\text{dB}}$ versus $f_{\text{RF}}$ and $T_{\text{mb}}$	12
Fig 14.	$\text{ICP}_{1\text{dB}}$ versus $f_{\text{RF}}$ and $P_{i(\text{lo})}$	12
Fig 15.	$\text{ICP}_{1\text{dB}}$ versus $f_{\text{RF}}$ and $V_{\text{CC}}$	12
Fig 16.	2RF-2LO response versus $f_{\text{RF}}$ and $T_{\text{mb}}$	13
Fig 17.	2RF-2LO response versus $f_{\text{RF}}$ and $P_{i(\text{lo})}$	13
Fig 18.	2RF-2LO response versus $f_{\text{RF}}$ and $V_{\text{CC}}$	13
Fig 19.	$a_{\text{isol}}$ versus $f_{\text{RF}}$ and $T_{\text{mb}}$	14
Fig 20.	$a_{\text{isol}}$ versus $f_{\text{RF}}$ and $P_{i(\text{lo})}$	14
Fig 21.	$a_{\text{isol}}$ versus $f_{\text{RF}}$ and $V_{\text{CC}}$	14
Fig 22.	Package outline SOT1092-2 (HVQFN36)	15

## 21. Contents

<b>1</b>	<b>General description</b>	<b>1</b>
<b>2</b>	<b>Features and benefits</b>	<b>1</b>
<b>3</b>	<b>Applications</b>	<b>1</b>
<b>4</b>	<b>Ordering information</b>	<b>1</b>
<b>5</b>	<b>Functional diagram</b>	<b>2</b>
<b>6</b>	<b>Pinning information</b>	<b>2</b>
6.1	Pinning	2
6.2	Pin description	3
<b>7</b>	<b>Functional description</b>	<b>4</b>
7.1	Power-up control	4
<b>8</b>	<b>Limiting values</b>	<b>5</b>
<b>9</b>	<b>Thermal characteristics</b>	<b>5</b>
<b>10</b>	<b>Static characteristics</b>	<b>5</b>
<b>11</b>	<b>Dynamic characteristics</b>	<b>6</b>
<b>12</b>	<b>Application information</b>	<b>8</b>
<b>13</b>	<b>Test information</b>	<b>9</b>
<b>14</b>	<b>Package outline</b>	<b>15</b>
<b>15</b>	<b>Abbreviations</b>	<b>16</b>
<b>16</b>	<b>Revision history</b>	<b>16</b>
<b>17</b>	<b>Legal information</b>	<b>17</b>
17.1	Data sheet status	17
17.2	Definitions	17
17.3	Disclaimers	17
17.4	Trademarks	18
<b>18</b>	<b>Contact information</b>	<b>18</b>
<b>19</b>	<b>Tables</b>	<b>19</b>
<b>20</b>	<b>Figures</b>	<b>19</b>
<b>21</b>	<b>Contents</b>	<b>20</b>

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

© NXP B.V. 2012.

All rights reserved.

For more information, please visit: <http://www.nxp.com>

For sales office addresses, please send an email to: [salesaddresses@nxp.com](mailto:salesaddresses@nxp.com)

Date of release: 8 August 2012

Document identifier: BGX7221